

元智大學 100 學年度研究所 碩士班 招生試題卷

系(所)別： 電機工程學系碩  
士班

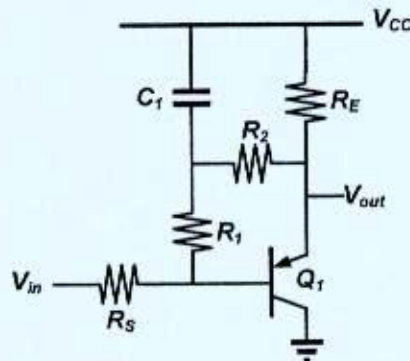
組別： 電子工程組

科目： 電子學

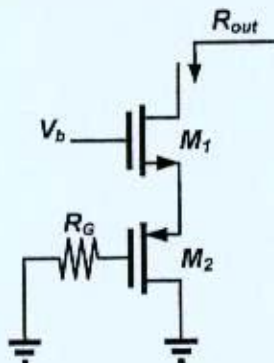
用紙第 / 頁共 2 頁

●不可使用電子計算機

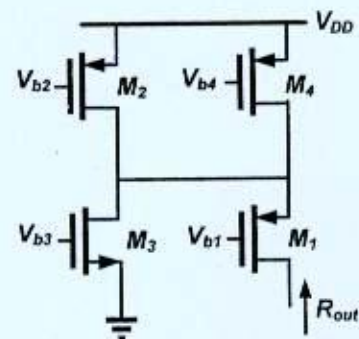
1. (20%) Please derive the (a) voltage gain (10%) (b) output impedance (10%) of the circuit shown below. Assume  $V_A \ll \infty$ ,  $C_1$  is quite large and the transconductance of  $Q_1$  is  $g_m$



2. (15%) Please derive the output impedance of the following circuit. Assume all of the transistors operate in saturation and  $g_{m1}r_{o1} = g_{m2}r_{o2} = g_{m3}r_{o3} = g_{m4}r_{o4} \gg 1$  and  $R_G = 200K\Omega$  (15%)

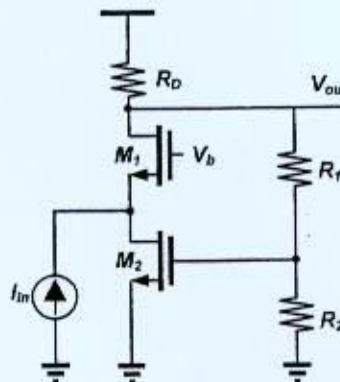


(a) (7%)



(b) (8%)

3. (20%) The amplifier of the following circuit is consisted of a single-stage amplifier and a feedback network. Assume  $R_1 + R_2$  is very large, the transconductance of  $M_1$  and  $M_2$  are  $g_{m1}$  and  $g_{m2}$ , respectively. Meanwhile all of the mosfets operate in saturation region and  $\lambda = 0$ . (a) What type of this single-stage amplifier which determine the open-loop gain of the circuit (2%) (b) what are the components forms the feedback network (3%) (c) please compute the closed-loop gain of this amplifier (10%) (d) please derive the closed-loop input impedance of this amplifier (5%).



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系(所)別： 電機工程學系碩士班      組別： 電子工程組      科目： 電子學      用紙第 2 頁共 2 頁

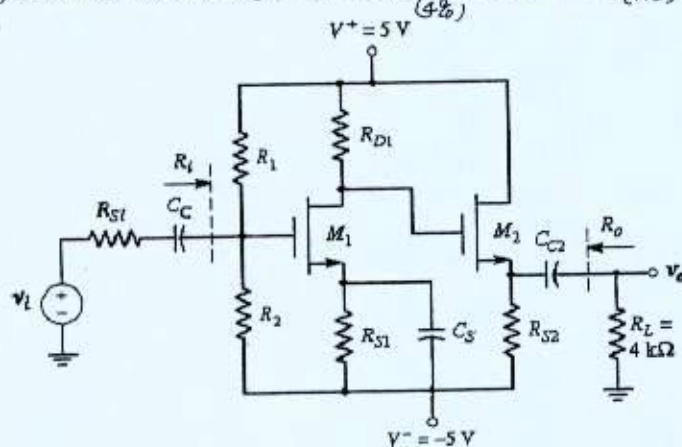
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4. (5%) Please use only NMOS construct following logic function (5%)

$$Z = \overline{(A+B)(C+D)}$$

5. (20%) Answer the following questions about the MOSFET multi-stage amplifier. (a) Explain the reasons that we use the multistage amplifier circuit? (4%) (b) What configuration is usually used to be the output stage? Why? (4%)

(c) Consider the following circuit with  $\frac{1}{2}k'_n(\frac{W}{L})_1 = 500 \mu\text{A}/\text{V}^2$ ,  $\frac{1}{2}k'_n(\frac{W}{L})_2 = 0.2 \text{ mA}/\text{V}^2$ ,  $V_{m1} = V_{m2} = 1.2\text{V}$ ,  $R_{S1} = 0\Omega$ , and  $\lambda_2 = \lambda_1 = 0$ . Design the circuit such that  $I_{DQ1} = 0.2\text{mA}$ ,  $I_{DQ2} = 0.5\text{mA}$ ,  $V_{DSQ1} = V_{DSQ2} = 6\text{V}$ , and  $R_f = 100\text{k}\Omega$ . (d) Determine the small-signal voltage gain. (e) determine  $R_O$ .



6. (20%) Consider the following BJT amplifier circuit, some properties of the voltage gain function  $H(s) = V_o(s)/V_{sig}(s)$  are to be investigated in the frequency domain. Neglect  $r_x$  and  $r_o$ . Please answer the following question in terms of small-signal parameters. (a) Sketch the equivalent circuits for low frequency, mid-band frequency, and high frequency, respectively (4%) (b) How many poles does  $H(s)$  have? Briefly explain your answer. (3%) (c) How many zeros does  $H(s)$  have? What are the frequencies of zeros? Briefly explain your answer. (3%) (d) Find the approximated lower 3-dB frequency by using time-constant technique. (5%) (e) Use the Miller's theorem to calculate the upper 3dB frequency. (5%)

